

NCP4547

ecoSwitch™ Advanced Load Management Controlled Load Switch with Low R_{ON}

The NCP4547 load switch provides a component and area-reducing solution for efficient power domain switching with inrush current limit via soft start. It is designed to integrate control and driver functionality with a high performance low on-resistance power MOSFET in a single device. This cost effective solution is ideal for power management and hot-swap applications requiring low power consumption in a small footprint.

Features

- Advanced Controller with Charge Pump
- Integrated N-Channel MOSFET with ESD Protection
- Soft-Start via Adjustable Slew Rate Control
- Low On-Resistance
- Input Voltage Range 0.5 V to 6 V
- Low Standby Current
- Load Bleed Function
- No External Components Required
- Enable Pins with CMOS Input Levels
- This is a Pb-Free Device

Typical Applications

- Notebook and Tablet Computers
- Handheld Electronics
- Digital Cameras
- Portable Medical Devices
- Hard Drives
- Peripheral Ports

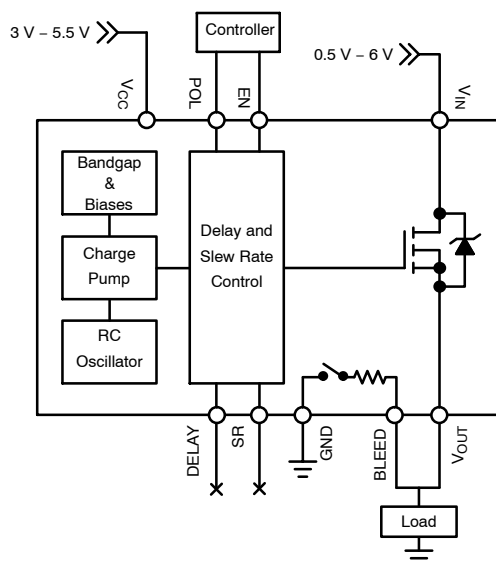


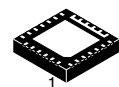
Figure 1. Typical Application – No external components included



ON Semiconductor®

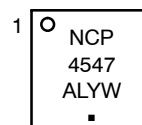
<http://onsemi.com>

R_{ON} TYP	V_{CC}	V_{IN}	I_{MAX}
4.7 mΩ	5.0 V	1.8 V	21.5 A
5.7 mΩ	3.3 V	5.0 V	



QFN26, 4x4
CASE 485BP

MARKING DIAGRAM



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping†
NCP4547IMNTWG	QFN26 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NCP4547

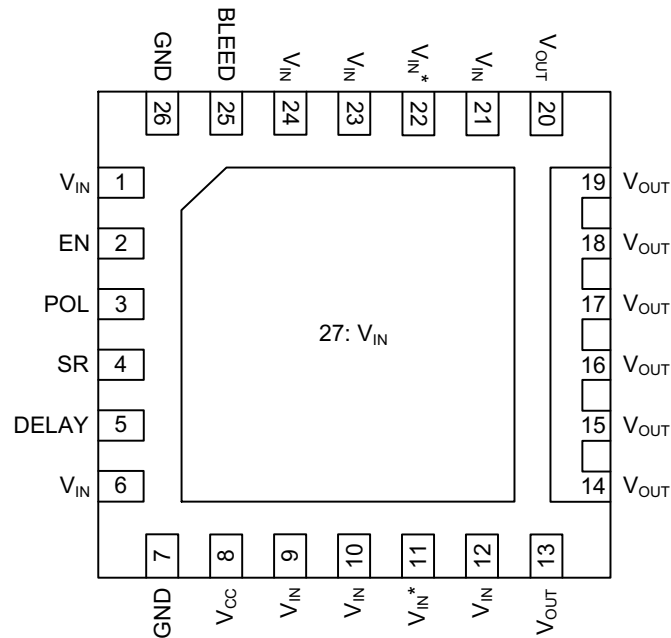


Figure 2. Pin Configuration – Top View

PIN DESCRIPTION

Pin	Name	Function															
1, 6, 9, 10, 12, 21, 23, 24, 27	V _{IN}	Drain of MOSFET (0.5 V – 6.0 V)															
2	EN	Digital input used to turn on the MOSFET according to this truth table: <table><tr><td>EN</td><td>POL</td><td>MOSFET</td></tr><tr><td>0</td><td>0</td><td>On</td></tr><tr><td>0</td><td>1</td><td>Off</td></tr><tr><td>1</td><td>0</td><td>Off</td></tr><tr><td>1</td><td>1</td><td>On</td></tr></table>	EN	POL	MOSFET	0	0	On	0	1	Off	1	0	Off	1	1	On
EN	POL	MOSFET															
0	0	On															
0	1	Off															
1	0	Off															
1	1	On															
3	POL	EN has an internal pull down resistor to GND POL has an internal pull up resistor to V _{CC}															
4	SR	Slew rate adjustment															
5	DELAY	Turn-on delay adjustment															
7, 26	GND	Controller ground															
8	V _{CC}	Supply voltage to controller (3.0 V – 5.5 V)															
11, 22	V _{IN} *	Internally floating but may be connected to V _{IN}															
13–20	V _{OUT}	Source of MOSFET connected to load															
25	BLEED	Load bleed connection															

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range	V_{CC}	-0.3 to 6	V
Input Voltage Range	V_{IN}	-0.3 to 6	V
Output Voltage Range	V_{OUT}	-0.3 to 6	V
EN/POL Digital Input Range	V_{EN}	-0.3 to ($V_{CC} + 0.3$)	V
Thermal Resistance, Junction-to-Air (Note 1)	$R_{\theta JA}$	40.5	°C/W
Thermal Resistance, Junction-to-Air (Note 2)	$R_{\theta JA}$	28.4	°C/W
Thermal Resistance, Junction-to-Case (V_{IN} Paddle)	$R_{\theta JC}$	1.37	°C/W
Continuous MOSFET Current (Note 3)	I_{MAX}	21.5	A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Notes 1 and 4) Derate above $T_A = 25^\circ\text{C}$	P_D	1.61 24.7	W mW/°C
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Notes 2 and 4) Derate above $T_A = 25^\circ\text{C}$	P_D	2.29 35.2	W mW/°C
Storage Temperature Range	T_{STG}	-40 to 150	°C
Lead Temperature, Soldering (10 sec.)	T_{SLD}	260	°C
ESD Capability, Human Body Model (Note 5)	ESD_{HBM}	3.5	kV
ESD Capability, Machine Model (Note 5)	ESD_{MM}	200	V
ESD Capability, Charged Device Model (Note 5)	ESD_{CDM}	1	kV
Latch-up Current Immunity (Note 5)	LU	100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.
2. Surface-mounted on FR4 board using 1 sq-in pad, 1 oz Cu.
3. Current limited by package.
4. Specified for derating purposes only, ensure that I_{MAX} is never exceeded.
5. Tested by the following methods @ $T_A = 25^\circ\text{C}$:
 ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
 ESD Machine Model tested per EIA/JESD22-A115
 ESD Charged Device Model per ESD-STM5.3.1-1999
 Latch-up Current Maximum Rating: ≤ 100 mA per JEDEC standard: JESD78

OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	3	5.5	V
Input Voltage	V_{IN}	0.5	6	V
Ground	GND		0	V
Ambient Temperature	T_A	0	70	°C
Junction Temperature	T_J	0	90	°C

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ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
MOSFET						
On-Resistance	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$	R_{ON}		4.7	6.1	$\text{m}\Omega$
	$V_{CC} = 5.0\text{ V}; V_{IN} = 5.0\text{ V}$			4.9	6.3	
	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$			5.1	6.5	
	$V_{CC} = 3.3\text{ V}; V_{IN} = 5.0\text{ V}$			5.7	7.1	
Leakage Current (Note 6)	$V_{EN} = 0\text{ V}; V_{POL} = V_{CC}; V_{IN} = 6\text{ V}$	I_{LEAK}		0.03	1.0	μA

CONTROLLER

Supply Standby Current (Note 7)	$V_{EN} = 0\text{ V}; V_{POL} = V_{CC} = 5.5\text{ V}$	I_{STBY}		5.0	15	μA
Supply Dynamic Current (Note 8)	$V_{EN} = V_{POL} = V_{CC}$	I_{DYN}		250	500	μA
Bleed Resistance		R_{BLEED}	50	100	200	Ω
Input High Voltage – EN & POL		V_{IH}	2.0			V
Input Low Voltage – EN & POL		V_{IL}			0.8	V
Pull Down Resistance – EN		R_{PD}	40	100	180	$\text{k}\Omega$
Pull Up Resistance – POL		R_{PU}	40	100	180	$\text{k}\Omega$

6. Average current from V_{IN} to V_{OUT} with MOSFET turned off.

7. Average current from V_{CC} to GND with MOSFET turned off.

8. Average current from V_{CC} to GND after charge up time of MOSFET.

SWITCHING CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified, Note 9)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
$V_{CC} = 5.0\text{ V}, V_{IN} = 1.8\text{ V}$						
Output Slew Rate	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	SR		8.2		kV/s
Output Turn-on Delay	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	T_{ON}		600		μs
Output Turn-off Delay	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	T_{OFF}		2.5		μs

$V_{CC} = 3.3\text{ V}, V_{IN} = 5.0\text{ V}$

Output Slew Rate	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	SR		4.3		kV/s
Output Turn-on Delay	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	T_{ON}		1300		μs
Output Turn-off Delay	$R_L = 10\ \Omega, C_L = 0.1\ \mu\text{F}$	T_{OFF}		1.1		μs

9. See below figure for Test Circuit and Timing Diagrams.

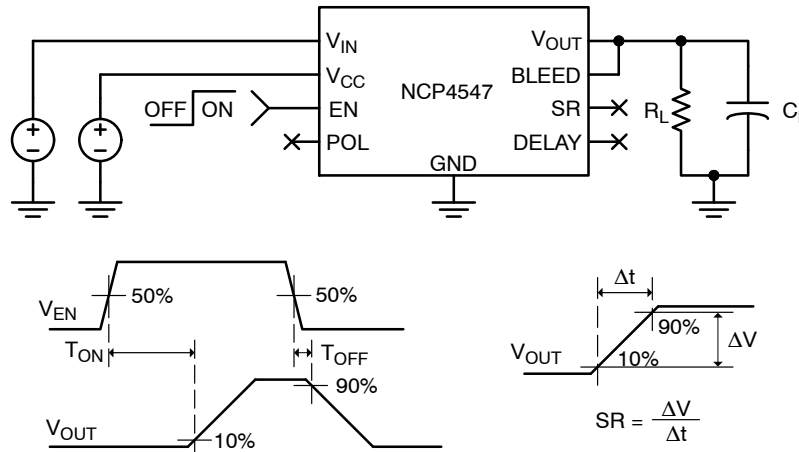


Figure 3. Test Circuit and Timing Diagrams

TYPICAL CHARACTERISTICS

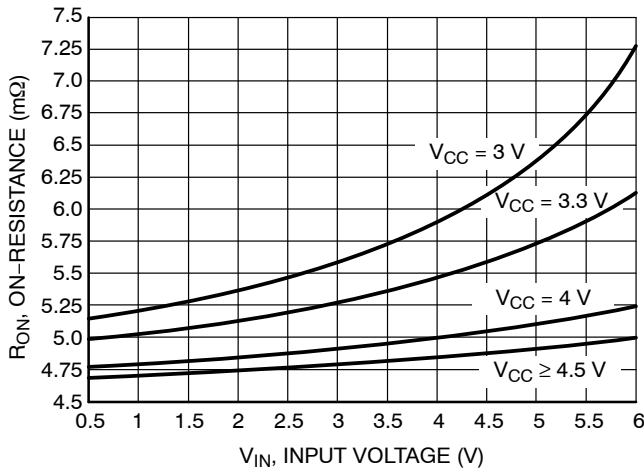


Figure 4. On-Resistance vs. Input Voltage

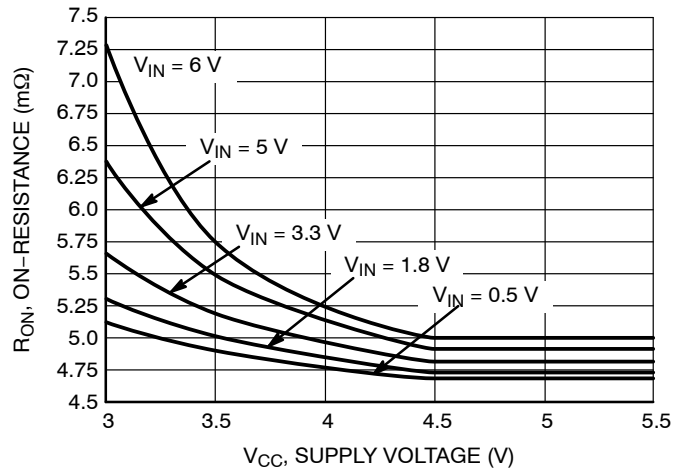


Figure 5. On-Resistance vs. Supply Voltage

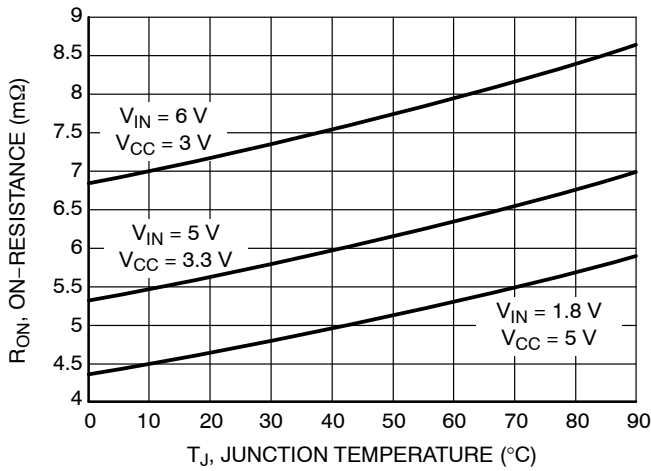


Figure 6. On-Resistance vs. Temperature

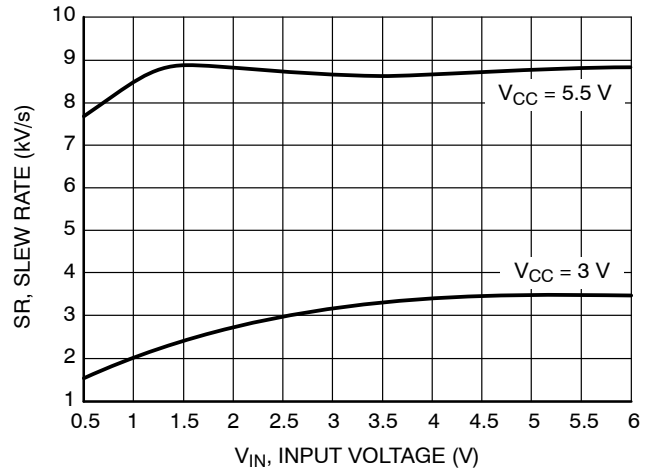


Figure 7. Slew Rate vs. Input Voltage

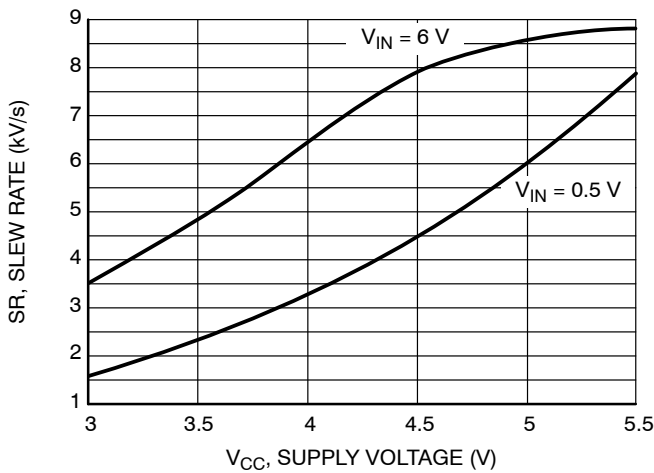


Figure 8. Slew Rate vs. Supply Voltage

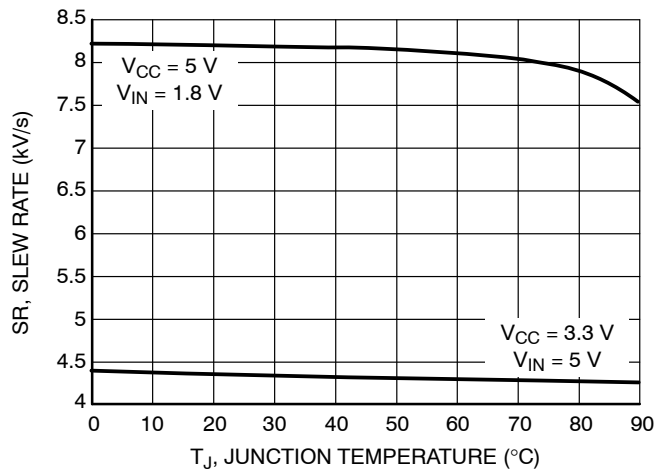


Figure 9. Slew Rate vs. Temperature

TYPICAL CHARACTERISTICS

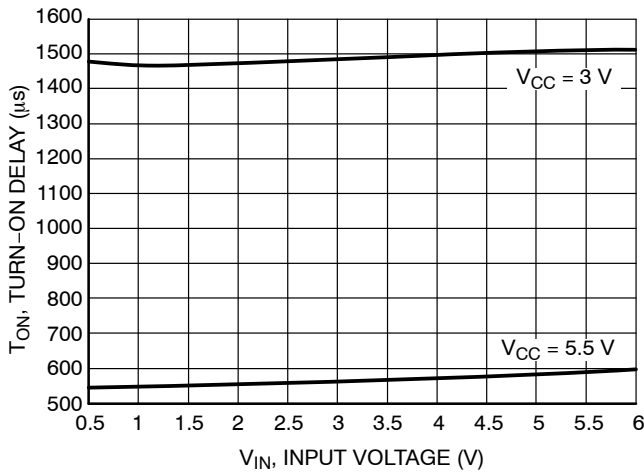


Figure 10. Turn-On Delay vs. Input Voltage

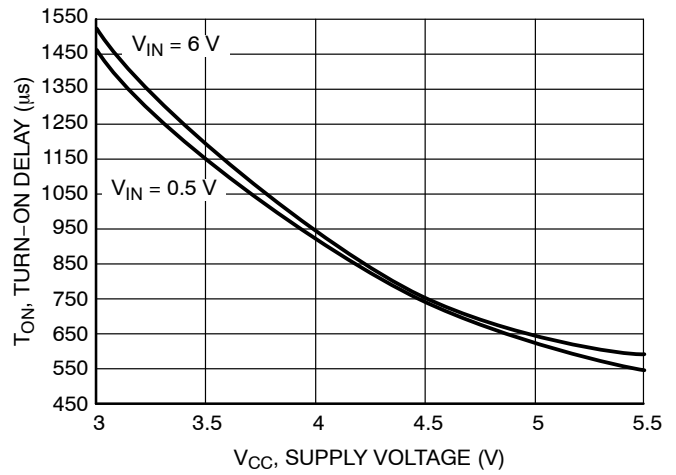


Figure 11. Turn-On Delay vs. Supply Voltage

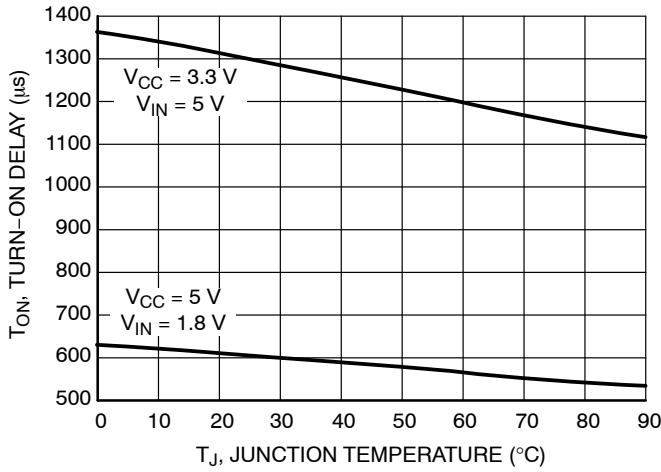


Figure 12. Turn-On Delay vs. Temperature

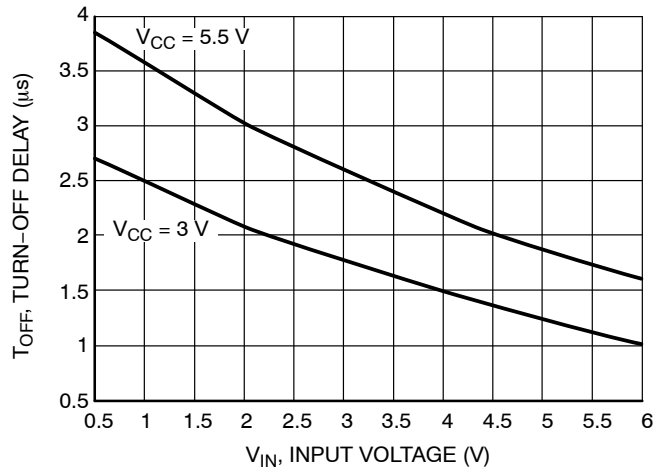


Figure 13. Turn-Off Delay vs. Input Voltage

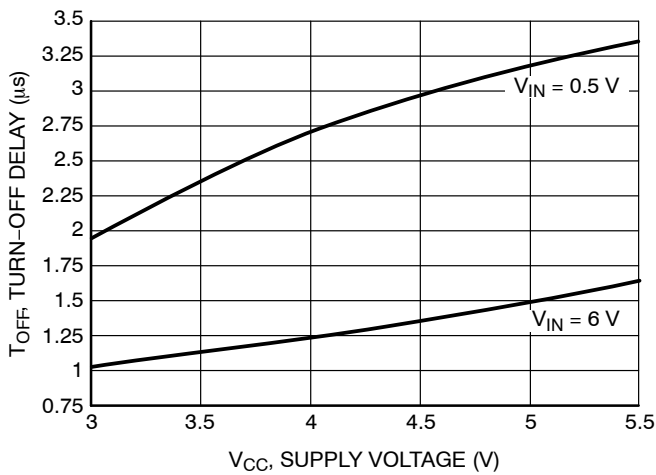


Figure 14. Turn-Off Delay vs. Supply Voltage

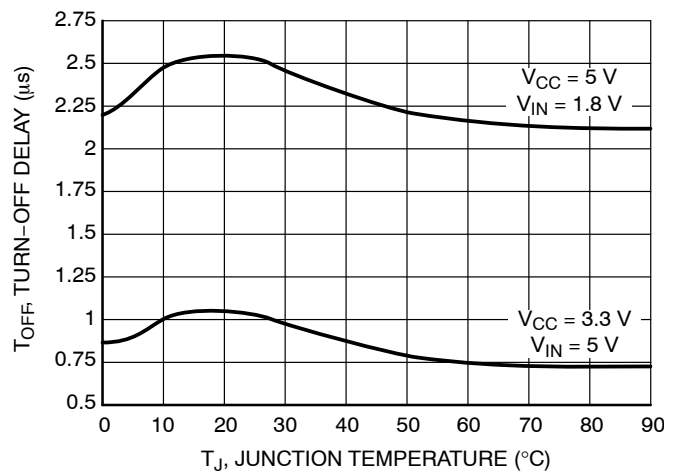


Figure 15. Turn-Off Delay vs. Temperature

TYPICAL CHARACTERISTICS

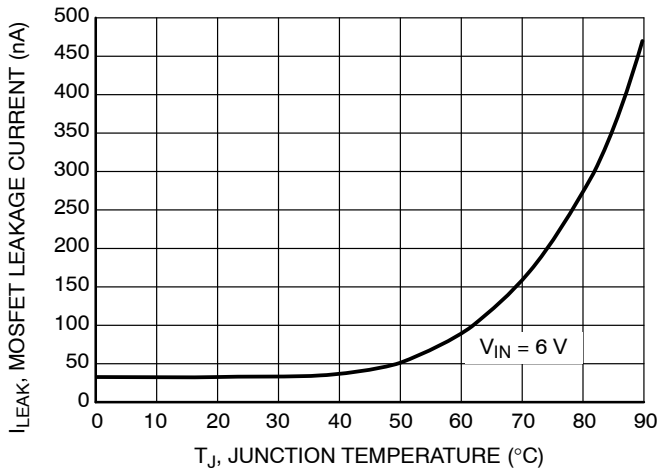


Figure 16. MOSFET Leakage Current vs. Temperature

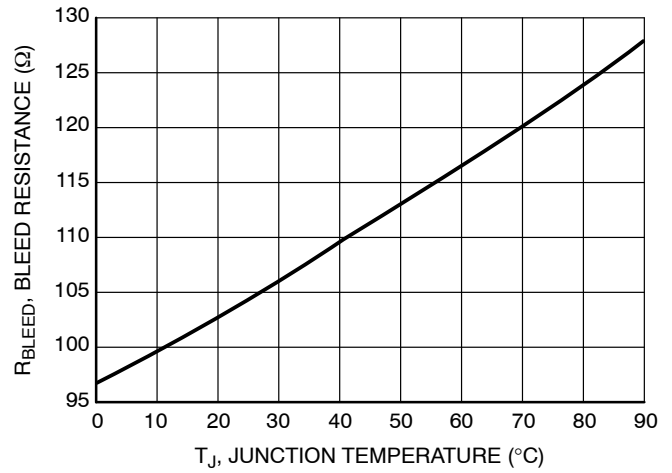


Figure 17. Bleed Resistance vs. Temperature

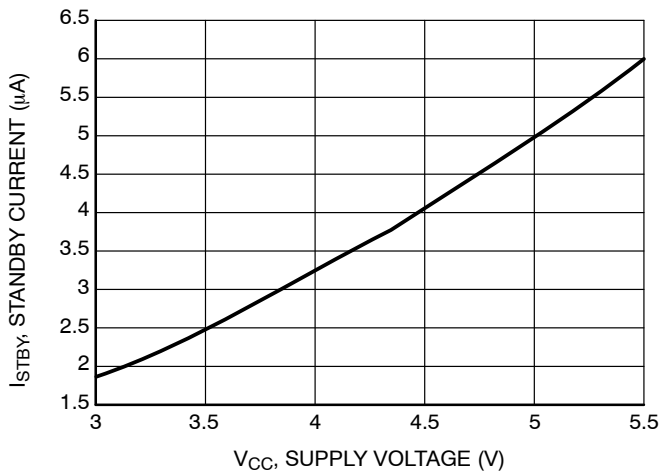


Figure 18. Standby Current vs. Supply Voltage

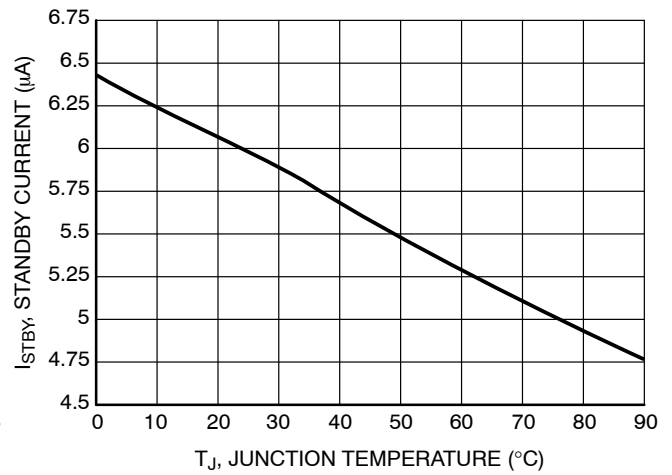


Figure 19. Standby Current vs. Temperature

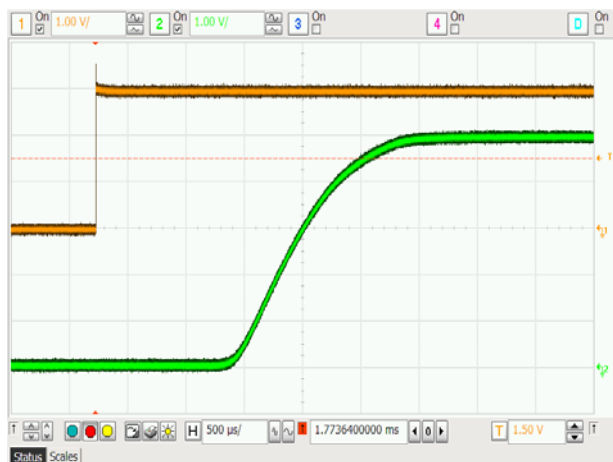


Figure 20. Turn-on Response
(V_{CC} = 3.3 V, V_{IN} = 5.0 V, R_L = 10 Ω, C_L = 0.1 μF)

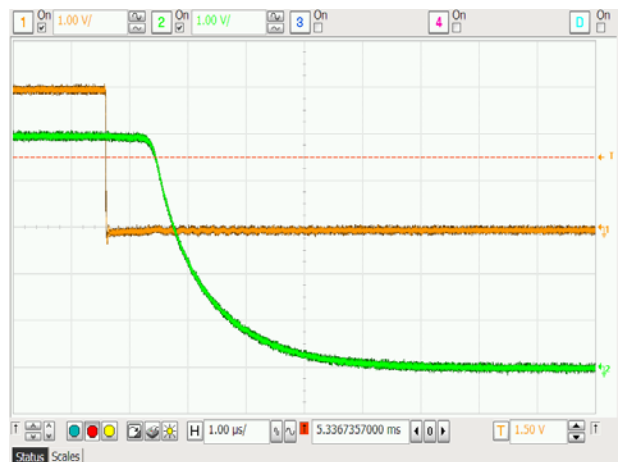


Figure 21. Turn-off Response
(V_{CC} = 3.3 V, V_{IN} = 5.0 V, R_L = 10 Ω, C_L = 0.1 μF)

APPLICATIONS INFORMATION

On-Resistance

The MOSFET gate voltage in the NCP4547 is driven by a charge pump in the controller circuit. The output voltage of the charge pump is dependent on the voltage on V_{CC} . The R_{ON} of the MOSFET is in turn dependent on its V_{GS} . Care must be taken to ensure a sufficient V_{CC} voltage is used to create the desired R_{ON} given the anticipated input voltage.

Enable Control

The NCP4547 allows for enabling the MOSFET in either an active-high or active-low configuration. When the EN and POL pins are both at a logic high level or both at a logic low level and the V_{CC} supply pin has an adequate voltage applied, the MOSFET will be enabled. Similarly, when the EN and POL pins are at different logic levels, the MOSFET will be disabled.

An internal pull down resistor on the EN pin and an internal pull up resistor on the POL pin ensure that the MOSFET will be disabled when neither pin is driven. The internal pull down or pull up resistor can also be used to allow for only one of the pins to be driven in either an active-high or active-low state.

Parametric Adjustments

The NCP4547 can be used in several configurations depending on the need to control turn-on delay, slew rate, and bleed resistance. Default minimum values of each parameter are built into the part without the requirement of external components. This configuration is shown above in Figure 1.

Figures 22 and 23 show alternate configurations where external components are used to modify the turn-on delay, slew rate, and total bleed resistance.

Figure 22 shows an external capacitor, C_{COMBO} , connected from the V_{OUT} pin to both the DELAY and SR pins. This allows for one external capacitor to be used to modify the turn-on delay and slew rate. Note that the value of C_{COMBO} is used in Equations 1 and 2 (below) in place of C_{DEL} and C_{SR} respectively.

Figure 23 shows the use of two external capacitors for independent control of the turn-on delay and slew rate.

Turn-On Delay

The NCP4547 provides a time delay between the input transitions on EN (or POL) to the MOSFET turning on. The

turn-on delay can be increased with an external capacitor added between the DELAY pin and either ground or the V_{OUT} pin as shown in Figures 22 and 23.

The total delay is calculated by adding the default turn-on delay to a delta term which is calculated as follows:

$$\Delta t = K_{DEL} * C_{DEL} \quad (\text{eq. 1})$$

where K_{DEL} is a constant and C_{DEL} is the off-chip capacitance added between the DELAY pin to either ground or the V_{OUT} pin (see table below). When no external capacitor is present, the delay will be the specified default turn-on delay.

Slew Rate Control

The NCP4547 is equipped with controlled output slew rate which provides soft start functionality. This limits the inrush current caused by capacitor charging and enables this device to be used in hot swapping applications. The slew rate can be decreased with an external capacitor added between the SR pin and the V_{OUT} pin as shown in Figures 22 and 23.

The slew rate can be calculated as follows:

$$SR = \frac{K_{SR}}{C_{SR} + C_{CHIP}} \quad (\text{eq. 2})$$

where K_{SR} is a constant, C_{SR} is the off-chip capacitance added between the SR pin and the V_{OUT} pin, and C_{CHIP} is the on-chip capacitance (see table below). Note that this equation is only valid for $C_{SR} \geq 470$ pF. When no external capacitor is present, the slew rate will be the specified default slew rate.

Load Bleed

The NCP4547 has an on-chip bleed resistor that can be used to bleed the charge off of the load to ground after the MOSFET has been disabled. In series with the bleed resistor is a bleed switch which is enabled whenever the MOSFET is disabled. Delays are added to the enable of this switch to ensure that both the MOSFET and the bleed switch are not concurrently active. The total bleed resistance can be increased by adding a resistor between the BLEED pin and the V_{OUT} pin as shown in Figures 22 and 23. If the load bleed function is not desired, the BLEED pin should be tied to ground or left floating.

SLEW RATE AND TURN-ON DELAY

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Turn-on Delay Constant		K_{DEL}		1.65		MΩ
External Delay Capacitance (Note 10)	Between DEL pin and GND	C_{DEL}			10	nF
Slew Rate Constant		K_{SR}		1.43		μA
External Slew Rate Capacitance (Note 10)	Between SR pin and V_{OUT} pin	C_{SR}			2	nF
Internal Slew Rate Capacitance		C_{CHIP}		150		pF
External Combo Capacitance (Note 10)	Between SR & DEL pins and V_{OUT} pin	C_{COMBO}			2	nF

10. Recommended range, larger values may be used but may degrade the performance of the part

NCP4547

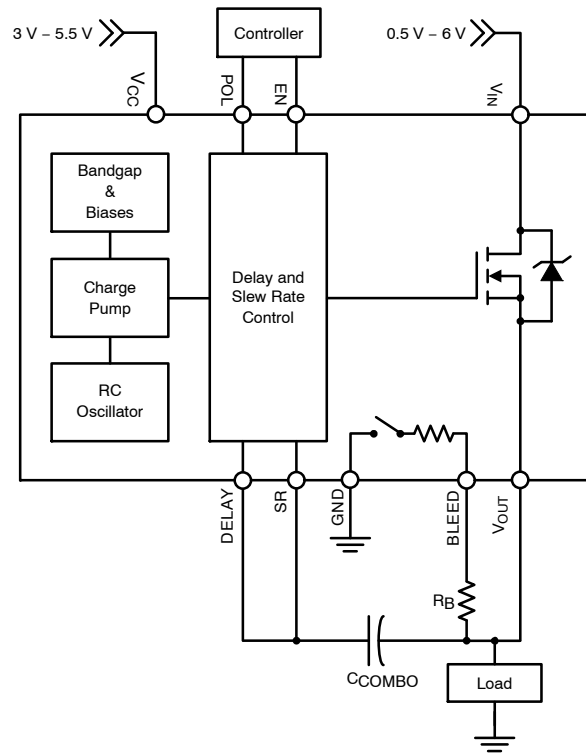


Figure 22. Example Application – External bleed resistor with single-capacitor adjustment of turn-on delay and slew rate.

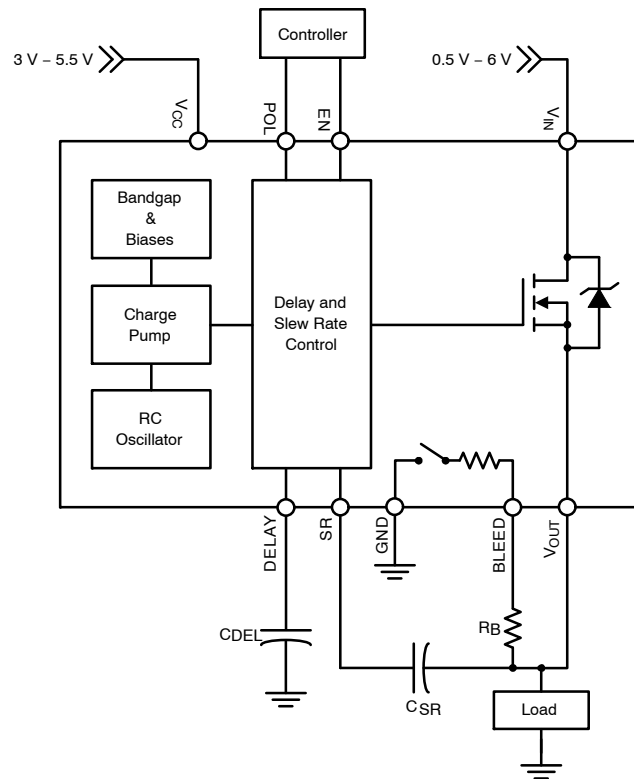
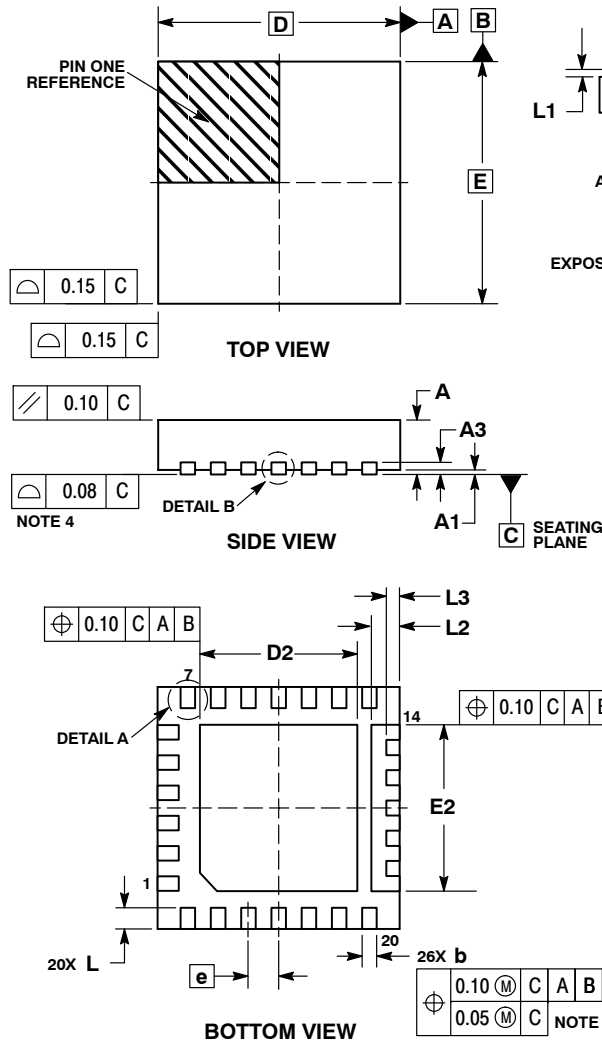


Figure 23. Example Application – External bleed resistor with independent adjustment of turn-on delay and slew rate.

NCP4547

PACKAGE DIMENSIONS

QFN26, 4x4, 0.5P
CASE 485BP
ISSUE O

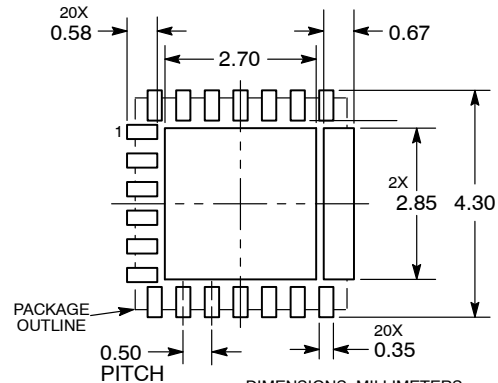


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.15 REF	
b	0.20	0.30
D	4.00 BSC	
D2	2.50	2.70
E	4.00 BSC	
E2	2.65	2.85
e	0.50 BSC	
L	0.25	0.45
L1	0.05	0.15
L2	0.37	0.57
L3	0.22 REF	

RECOMMENDED MOUNTING FOOTPRINT*



*This Solder Mask is defined only for this layout.

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<http://moschip.ru/get-element>

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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